WHAT IS CLAIMED IS:

- 1. A delay circuit comprising:
 - a clocked inverter circuit to which a first pulse signal is supplied; and
- a logic circuit to which a second pulse signal outputted from said clocked inverter circuit and an inverted signal of said first pulse signal are supplied, wherein

said clocked inverter circuit changes a pulse width of said first pulse signal in a direction opposite to a direction in which a pulse width of a third pulse signal outputted from said logic circuit changes.

- 2. The delay circuit according to claim 1, wherein said logic circuit is a NOR circuit and said clocked inverter circuit delays a trailing edge of said third pulse signal.
- 3. The delay circuit according to claim 1, wherein said logic circuit is a NAND circuit and said clocked inverter circuit delays a leading edge of said third pulse signal.
- 4. The delay circuit according to claim 1, wherein said clocked inverter circuit is composed of an NMOS transistor and a PMOS transistor and at least one of a channel width, channel length, threshold voltage, and substrate voltage of the NMOS is different from a channel width, channel length, threshold voltage, and substrate voltage of the PMOS transistors.
- 5. The delay circuit according to claim 4, wherein a ratio of a current driving capability of said PMOS transistor to a current driving capability of said NMOS transistor is set to a value other than one and a rise time of a pulse signal is made different from a decay time of the pulse signal.
- 6. A delay circuit comprising:

an inverter circuit controlled by a clock signal to which a first pulse signal is supplied; and

a logic circuit to which a second pulse signal outputted from said inverter circuit and an inverted signal of said first pulse signal are supplied, wherein

said inverter circuit changes a pulse width of said first pulse signal in a direction opposite to a direction in which a pulse width of a third pulse signal outputted from said logic circuit changes.